

# MPXH6400A, 20 to 400 kPa, Absolute, Integrated Pressure Sensor

The NXP MPXxx6400A series sensor integrates on-chip, bipolar op amp circuitry and thin film resistor networks to provide a high output signal and temperature compensation. The small form factor and high reliability of on-chip integration make this pressure sensor a logical and economical choice for the system designer.

The MPXxx6400A series piezoresistive transducer is a state-of-the-art, monolithic, signal conditioned, silicon pressure sensor. This sensor combines advanced micromachining techniques, thin film metallization, and bipolar semiconductor processing to provide an accurate, high level analog output signal that is proportional to applied pressure.

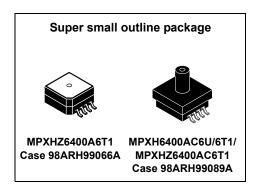
#### **Features**

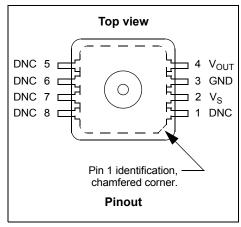
- Improved accuracy at high temperature
- Available in super small outline package
- 1.5% maximum error over 0 °C to 85 °C
- Fully calibrated and compensated
- Ideally suited for microprocessor or microcontroller-based systems
- Temperature compensated from -40 °C to +125 °C
- Durable thermoplastic surface mount package
- Package porting and mounting options enable tube attachment for liquefied natural gas (LPG) or remote sensing applications

### Typical applications

- · Fuel injected car engines
- Vehicles powered by green gases (for example LPG and CNG)
- Small engines
- · Industrial controls

# MPXH6400A





Ordering information									
Dout number	Chinning	Dookone			# of Ports		Pressure type		Device
Part number	Shipping	Package	None	Single	Dual	Gauge	Differential	Absolute	marking
Super Small Outline F	Package (Media	resistant gel)							
MPXH6400AC6U	Rail	98ARH99089A		•				•	MPXH6400A
MPXH6400AC6T1	Tape and Reel	98ARH99089A		•				•	MPXH6400A
MPXHZ6400A6T1	Tape and Reel	98ARH99066A	•					•	MPXHZ6400A
MPXHZ6400AC6T1	Tape and Reel	98ARH99089A		•				•	MPXHZ6400A

NXP reserves the right to change the detail specifications as may be required to permit improvements in the design of its products.

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## **Related Documentation**

The MPXxx6400A device features and operations are described in a variety of reference manuals, user guides, and application notes. To find the most-current versions of these documents:

# 1 General Description

## 1.1 Block diagram

Figure 1 shows a block diagram of the internal circuitry integrated on a pressure sensor chip.

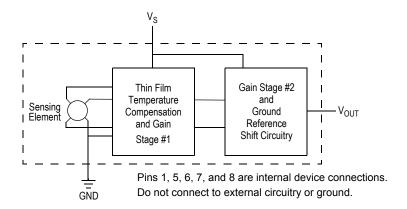


Figure 1. Integrated pressure sensor block diagram

## 1.2 Pinout

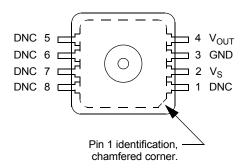


Figure 2. Device pinout (top view)

**Table 1. Pin functions** 

Pin	Name	Function
1	DNC	Do not connect to external circuitry or ground. Pin 1 is notated by chamfered corner.
2	V <sub>S</sub>	Voltage supply
3	GND	Ground
4	V <sub>OUT</sub>	Output voltage
5	DNC	Do not connect to external circuitry or ground.
6	DNC	Do not connect to external circuitry or ground.
7	DNC	Do not connect to external circuitry or ground.
8	DNC	Do not connect to external circuitry or ground.

#### **Mechanical and Electrical Specifications** 2

#### 2.1 **Maximum ratings**

Table 2. Maximum ratings<sup>(1)</sup>

Parametrics	Symbol	Value	Units
Maximum pressure (P1 > P2)	P <sub>MAX</sub>	1600	kPa
Storage temperature	T <sub>STG</sub>	-40° to +125°	°C
Operating temperature	T <sub>A</sub>	-40° to +125°	°C
Output source current @ full-scale output(2)	I <sub>O</sub> +	0.5	mAdc
Output sink current @ minimum pressure offset <sup>(2)</sup>	I <sub>O</sub> -	-0.5	mAdc

<sup>1.</sup> Exposure beyond the specified limits may cause permanent damage or degradation to the device.

#### 2.2 Operating characteristics

Table 3. Operating characteristics ( $V_S = 5.0 V_{DC}$ ,  $T_A = 25 ^{\circ}C$  unless otherwise noted, P1 > P2.)

Characteristic	Symbol	Min	Тур	Max	Unit
Pressure range	P <sub>OP</sub>	20	_	400	kPa
Supply voltage <sup>(1)</sup>	V <sub>S</sub>	4.64	5.0	5.36	$V_{DC}$
Supply current	Io	_	6.0	10	mAdc
Minimum pressure offset <sup>(2)</sup> (0 to 85 °C) @ $V_S$ = 5.0 Volts	V <sub>OFF</sub>	0.133	0.2	0.267	$V_{DC}$
Full-scale output <sup>(3)</sup> (0 to 85 °C) @ $V_S$ = 5.0 Volts	V <sub>FSO</sub>	4.733	4.8	4.866	$V_{DC}$
Full-scale span <sup>(4)</sup> (0 to 85 °C) @ V <sub>S</sub> = 5.0 Volts	V <sub>FSS</sub>	4.467	4.6	4.733	V <sub>DC</sub>
Accuracy <sup>(5)</sup> (0 to 85 °C)	_	_	_	±1.5	%V <sub>FSS</sub>
Sensitivity	V/P	_	12.1	_	mV/kPa
Response time <sup>(6)</sup>	t <sub>R</sub>	_	1.0	_	ms
Warm-up time <sup>(7)</sup>	_	_	20	_	ms
Offset stability <sup>(8)</sup>	_	_	±0.25	_	%V <sub>FSS</sub>

<sup>1.</sup> Device is ratiometric within this specified excitation range.

Linearity: Output deviation from a straight line relationship with pressure over the specified pressure range.

Temperature hysteresis: Output deviation at any temperature within the operating temperature range, after the temperature is cycled to and from the minimum or maximum operating temperature points, with zero differential pressure applied.

Pressure hysteresis: Output deviation at any pressure within the specified range, when this pressure is cycled to and from minimum or maximum rated pressure at 25 °C

TcSpan: Output deviation over the temperature range of 0 to 85 °C, relative to 25 °C.

TcOffset: Output deviation with minimum rated pressure applied, over the temperature range of 0 to 85 °C, relative to 25 °C.

Variation from Nominal: The variation from nominal values, for offset or full-scale span, as a percent of V<sub>FSS</sub>, at 25 °C.

- 6. Response time is defined as the time for the incremental change in the output to go from 10% to 90% of its final value when subjected to a specified step change in pressure.
- 7. Warm-up time is defined as the time required for the product to meet the specified output voltage after the pressure has been stabilized.
- 8.Offset stability is the product's output deviation when subjected to 1000 cycles of pulsed pressure, temperature cycling with bias test.

<sup>2.</sup>Maximum output current is controlled by effective impedance from V<sub>OUT</sub> to GND or V<sub>OUT</sub> to V<sub>S</sub> in the application circuit.

<sup>2.</sup>Offset (V<sub>OFF</sub>) is defined as the output voltage at the minimum rated pressure.

<sup>3.</sup>Full-scale output (V<sub>FSO</sub>) is defined as the output voltage at the maximum or full-rated pressure.

<sup>4.</sup> Full-scale span (V<sub>ESS</sub>) is defined as the algebraic difference between the output voltage at full-rated pressure and the output voltage at the minimum rated pressures

<sup>5.</sup> Accuracy is the deviation in actual output from nominal output over the entire pressure range and temperature range as a percent of span at 25 °C due to all sources of error including the following:

#### 3 **On-chip Temperature Compensation and Calibration**

Figure 3 illustrates the absolute sensing chip in the basic super small outline chip carrier (case 98ARH99066A).

Figure 4 shows a typical application circuit (output source current operation).

Figure 5 shows the sensor output signal relative to pressure input. Typical minimum and maximum output curves are shown for operation over 0 to 85 °C temperature range. The output will saturate outside of the rated pressure range.

A fluorosilicone gel isolates the die surface and wire bonds from the environment, while allowing the pressure signal to be transmitted to the silicon diaphragm. The MPXH6400A/MPXHZ6400A pressure sensor operating characteristics, internal reliability and qualification tests are based on use of dry air as the pressure media. Media other than dry air may have adverse effects on sensor performance and long-term reliability. Contact the factory for information regarding media compatibility in your application.

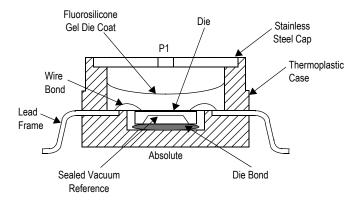


Figure 3. Cross-sectional diagram (not-to-scale)

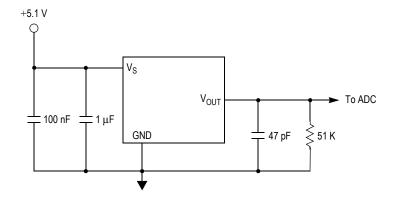


Figure 4. Recommended power supply decoupling and output filtering

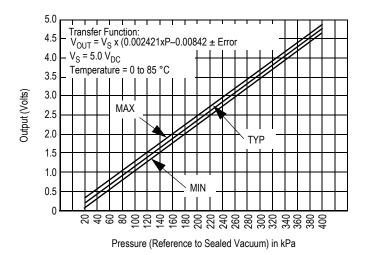


Figure 5. Output vs. absolute pressure

Normal Transfer Value:  $V_{OUT}$  =  $V_{S}$  x (0.002421 x P - 0.00842)  $\pm$  Pressure Error x Temp. Factor x 0.002421 x  $V_{S}$   $V_{S}$  = 5.0  $\pm$  0.36  $V_{DC}$ 

Figure 6. Transfer function

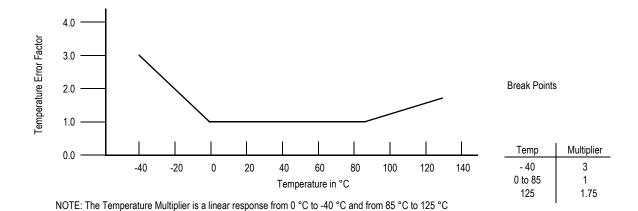


Figure 7. Temperature error band

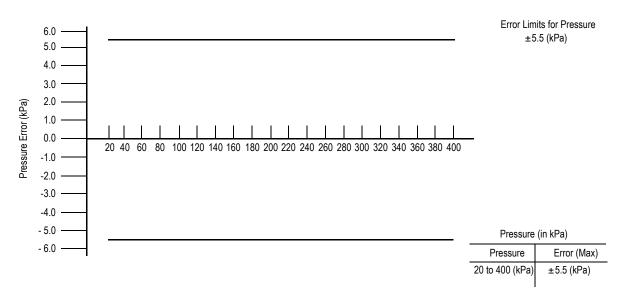


Figure 8. Pressure error band

# 4 Package Information

## 4.1 Minimum recommended footprint for surface mounted applications

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor package must be the correct size to ensure proper solder connection interface between the board and the package. With the correct pad geometry, the packages will self-align when subjected to a solder reflow process. It is always recommended to fabricate boards with a solder mask layer to avoid bridging and/or shorting between solder pads, especially on tight tolerances and/or tight layouts.

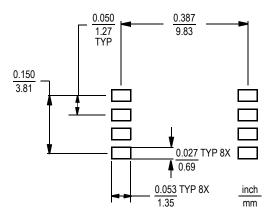
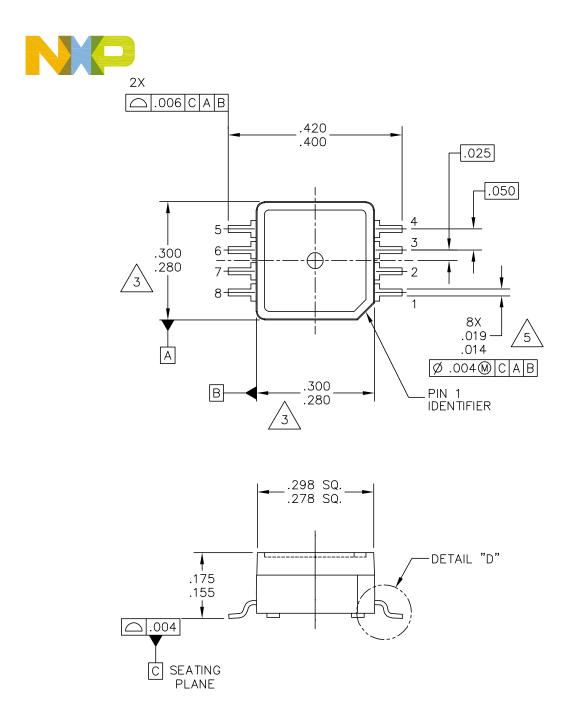


Figure 9. SSOP footprint

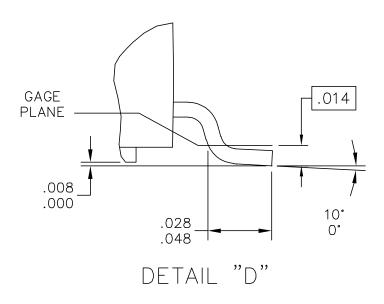
# 4.2 Package Dimensions



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	SSUB		STANDAF	RD: NON-JEDEC	
	3301		S0T1709	-1	01 FEB 2016

Case 98ARH99066A, super small outline package, surface mount





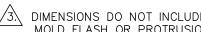
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		D	STANDAF	RD: NON-JEDEC	
	3301		S0T1709	-1	01 FEB 2016

Case 98ARH99066A, super small outline package, surface mount



#### NOTES:

- 1. ALL DIMENSIONS IN INCHES.
- 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.



DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSION SHALL NOT EXCEED .006 INCHES PER SIDE.

4. ALL VERTICAL SURFACES TO BE 5' MAXIMUM.

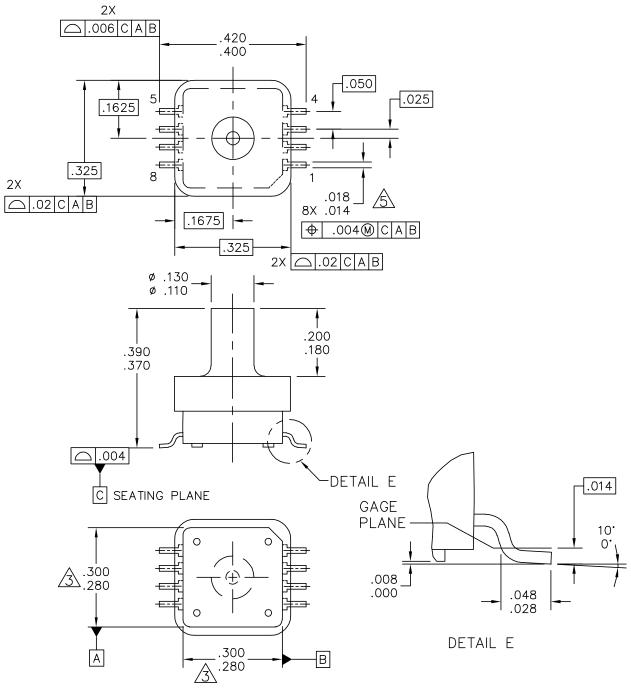


DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .008 INCHES MAXIMUM.

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Case 98ARH99066A, super small outline package, surface mount





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Case 98ARH99089A, small outline package, surface mount



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NXP SEMICONDUCTORS N. V. ALL RIGHTS RESERVED	MECHANICAL OUTLINE		PRINT VERSION NO	T TO SCALE
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		S0T1710	D-1	01 FEB 2016

Case 98ARH99089A, small outline package, surface mount

# 5 Revision History

## Table 4. Revision history

Document ID	Release Date	Data sheet status	Change notice	Supersedes	
MPXH6400A Rev. 6	2017 March	Technical data	_	MPXH6400A Rev. 5.0	
Modifications	<ul> <li>Revised V<sub>S</sub> = 10.0 V<sub>DC</sub> value to V<sub>S</sub> = 5.0 V<sub>DC</sub> in Table 3.</li> <li>The format of this data sheet has been redesigned to comply with current identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate.</li> <li>Updated package outlines Section 4.2, "Package Dimensions" to comply with current identity guidelines of NXP Semiconductors.</li> </ul>				
MPXH6400A Rev. 5.0	2015 September	Technical data	_	MPXH64-00A Rev.	